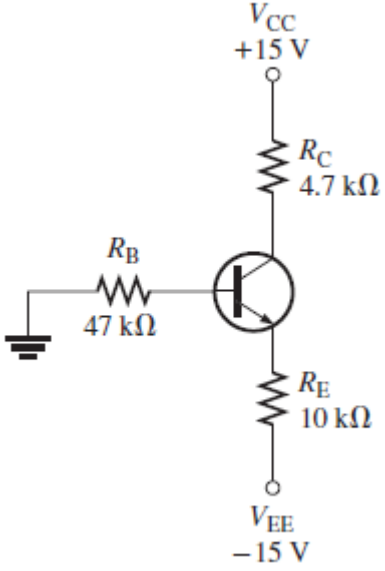


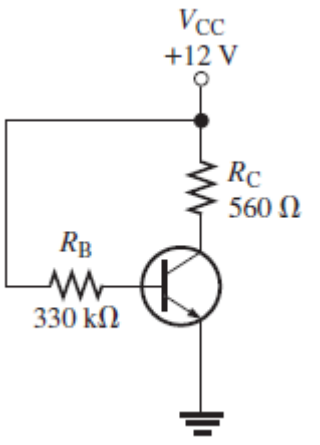
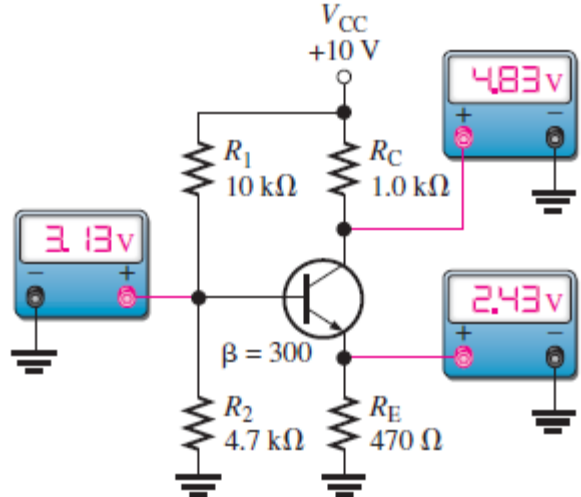
Electronic Circuits II - Tutorial 02

#		
1	Emitter bias uses one dc supply voltage.	F
2	Negative feedback is employed in collector-feedback bias.	T
3	Base bias is less stable than voltage-divider bias.	T
4	A pnp transistor requires bias voltage polarities opposite to an npn transistor	T

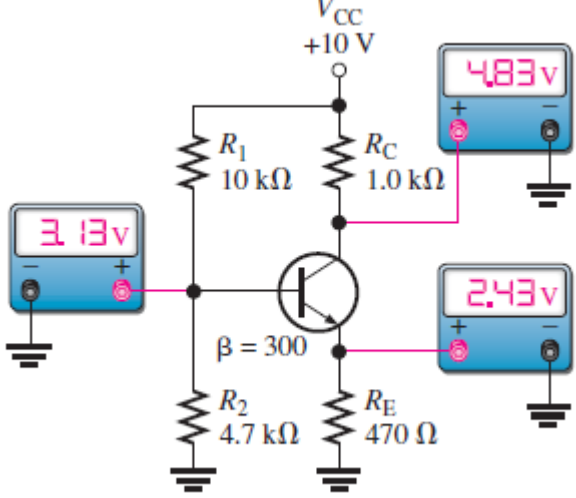
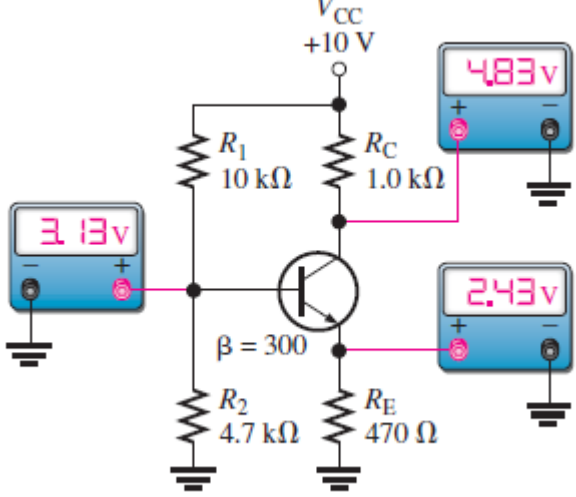
MCQ

#	Question	Answer
1	<p>If R_B in Figure is reduced, the base-to-emitter voltage will</p>  <p>(a) increase (b) decrease (c) not change</p>	C



2	<p>If V_{CC} in Figure is increased, the base-to-emitter voltage will</p>  <p>(a) increase (b) decrease (c) not change</p>	C
3	<p>If R_1 in Figure opens, the collector voltage will</p>  <p>(a) increase (b) decrease (c) not change</p>	A

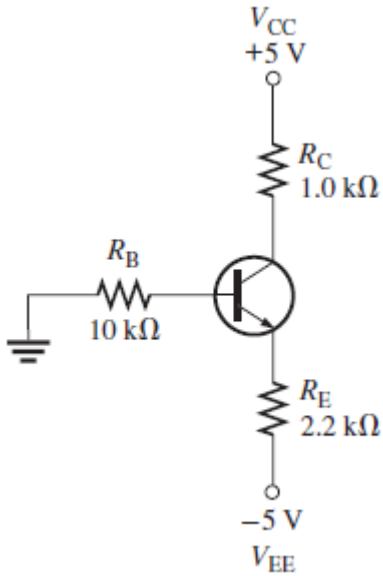


4	<p>If R_2 in Figure opens, the collector voltage will</p>  <p>(a) increase (b) decrease (c) not change</p>	B
5	<p>If R_2 in Figure is increased, the emitter current will</p>  <p>(a) increase (b) decrease (c) not change</p>	a



Q1

Analyze the circuit in Figure to determine the correct voltages at the transistor terminals with respect to ground. Assume $\beta_{DC} = 100$.



Sol
1

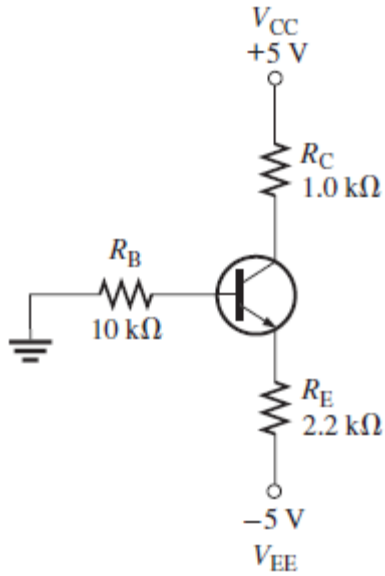
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... $V_B = -186 \text{ mV}; V_E = -0.886 \text{ V}; V_C = 3.14 \text{ V}$
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Q2

Taking V_{BE} into account in Figure how much will I_E change with a temperature increase from 25°C to 100°C ? The V_{BE} is 0.7 V at 25°C and decreases 2.5 mV per degree Celsius. Neglect any change in β_{DC} .



Sol
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... 0.09 mA

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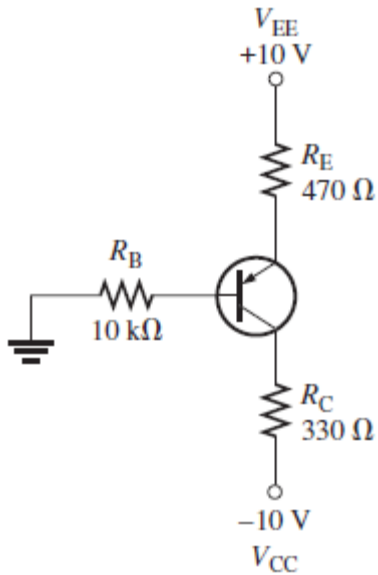


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Q3

Determine I_C and V_{CE} in the *pn*p emitter bias circuit of Figure . Assume $\beta_{DC} = 100$.



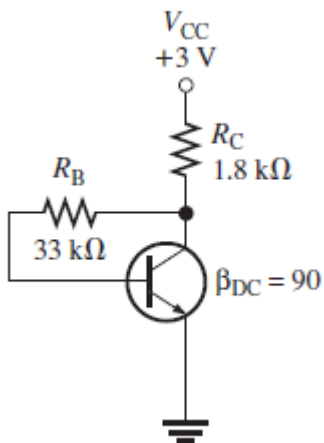
Sol
3

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..... $I_C = 16.3 \text{ mA}; V_{CE} = -6.95 \text{ V}$
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Q4

What value of R_C can be used to decrease I_C 25 percent?



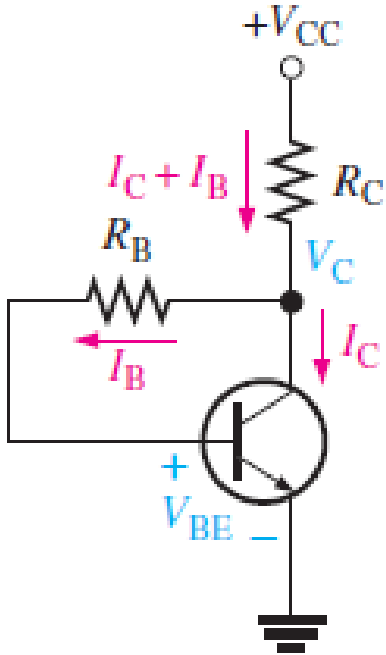
Sol
4

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..... **2.53 kΩ**
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Q5

A collector-feedback circuit uses an *npn* transistor with $V_{CC} = 12 \text{ V}$, $R_C = 1.2 \text{ k}\Omega$, and $R_B = 47 \text{ k}\Omega$. Determine the collector current and the collector voltage if $\beta_{DC} = 200$.



Sol
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... 7.87 mA; 2.56 V

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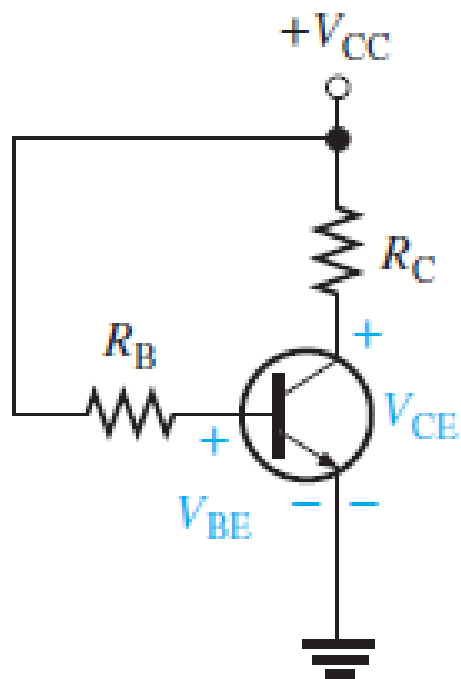


Q6

a base-biased transistor circuit with the following values:

$\beta_{DC} = 90$, $V_{CC} = 12 \text{ V}$, $R_B = 22 \text{ k}\Omega$, and $R_C = 100 \Omega$.

If β_{DC} in Problem doubles over temperature, what are the Q-point values?



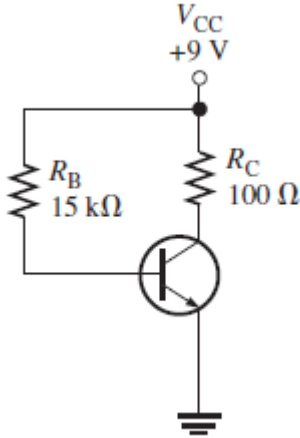
Sol
6

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 $I_{CQ} = 92.5 \text{ mA}$; $V_{CEQ} = 2.75 \text{ V}$



Q7

The datasheet for a particular transistor specifies a minimum β_{DC} of 50 and a maximum β_{DC} of 125. What range of Q-point values can be expected if an attempt is made to mass-produce the circuit in Figure ? Is this range acceptable if the Q-point must remain in the transistor's linear region?



Sol

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..... 27.7 mA to 69.2 mA; 6.23 V to 2.08 V; Yes

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